



Cite this: *RSC Adv.*, 2018, 8, 12211

# High-temperature thermoelectric properties of Na- and W-Doped $\text{Ca}_3\text{Co}_4\text{O}_9$ system

Uzma Hira,<sup>ab</sup> Li Han,<sup>b</sup> Kion Norrman,<sup>b</sup> Dennis Valbjørn Christensen,<sup>b</sup> Nini Pryds<sup>\*b</sup> and Falak Sher <sup>\*a</sup>

The detailed crystal structures and high temperature thermoelectric properties of polycrystalline  $\text{Ca}_{3-2x}\text{Na}_{2x}\text{Co}_{4-x}\text{W}_x\text{O}_9$  ( $0 \leq x \leq 0.075$ ) samples have been investigated. Powder X-ray diffraction data show that all samples are phase pure, with no detectable traces of impurity. The diffraction peaks shift to lower angle values with increase in doping ( $x$ ), which is consistent with larger ionic radii of  $\text{Na}^+$  and  $\text{W}^{6+}$  ions. X-ray photoelectron spectroscopy data reveal that a mixture of  $\text{Co}^{2+}$ ,  $\text{Co}^{3+}$  and  $\text{Co}^{4+}$  valence states are present in all samples. It has been observed that electrical resistivity ( $\rho$ ), Seebeck coefficient ( $S$ ) and thermal conductivity ( $\kappa$ ) are all improved with dual doping of Na and W in  $\text{Ca}_3\text{Co}_4\text{O}_9$  system. A maximum power factor (PF) of  $2.71 \times 10^{-4} \text{ W m}^{-1} \text{ K}^{-2}$  has been obtained for  $x = 0.025$  sample at 1000 K. The corresponding thermoelectric figure of merit ( $zT$ ) for  $x = 0.025$  sample is calculated to be 0.21 at 1000 K, which is  $\sim 2.3$  times higher than  $zT$  value of the undoped sample. These results suggest that Na and W dual doping is a promising approach for improving thermoelectric properties of  $\text{Ca}_3\text{Co}_4\text{O}_9$  system.

Received 26th February 2018

Accepted 23rd March 2018

DOI: 10.1039/c8ra01691g

rsc.li/rsc-advances

## 1. Introduction

Thermoelectric (TE) power generation from waste heat is considered as a promising renewable energy technology.<sup>1,2</sup> TE devices convert thermal energy into electricity *via* the Seebeck effect, and electrical power into solid state refrigeration *via* the Peltier effect.<sup>3</sup> In order to convert waste heat into electrical energy efficiently, good TE materials with high values of dimensionless figure of merit ( $zT$ ) are required:<sup>4</sup>

$$zT = \frac{S^2 T}{\rho \kappa} \quad (1)$$

where  $S$  ( $\text{V K}^{-1}$ ) is the Seebeck coefficient,  $T$  (K) is the absolute temperature,  $\rho$  ( $\Omega\text{m}$ ) is the electrical resistivity, and  $\kappa$  ( $\text{W m}^{-1} \text{K}^{-1}$ ) is the thermal conductivity.

For practical high waste heat to electricity conversion efficiency devices,  $zT > 1$  is an essential prerequisite. Therefore robust TE materials with large thermoelectric power factor:  $\text{PF} = S^2/\rho$  and smaller thermal conductivity are required. In addition, TE materials must be stable in air at high operating temperatures over a long period of time and should be made of earth-abundant low cost elements. Conventional thermoelectric materials such as  $\text{Bi}_2\text{Te}_3$  ( $T_{\text{max}} = 550 \text{ K}$ ),  $\text{SiGe}$  ( $T_{\text{max}} > 1300 \text{ K}$  expensive and oxidation sensitive) and half-Heusler compounds ( $T_{\text{max}} = 850 \text{ K}$ ) do not meet all requirements for high

temperature thermoelectric applications.<sup>5-7</sup> Transition metal oxides are promising candidates and have been explored for their potential applications in high temperature thermoelectric devices. A number of transition metal oxides such as  $\text{CaMnO}_3$ ,<sup>2</sup> Al-doped  $\text{ZnO}$ <sup>8</sup> and Ta-doped  $\text{SrTiO}_3$  (ref. 9) show good thermoelectric properties and are stable in air at high temperatures of around 1000 K. Moreover, metal oxides can be synthesized from non-toxic and inexpensive precursors<sup>10</sup> and can possibly segmented with non-oxide materials in TE modules to increase the efficiency of devices.<sup>11</sup> Consequently, significant research efforts have been recently devoted to the development of thermoelectric generators (TEGs) for automotive applications.<sup>12</sup> Among the transition metal oxides, misfit-layered cobaltites such as  $\text{Na}_x\text{CoO}_2$ ,<sup>13</sup>  $\text{Ca}_3\text{Co}_4\text{O}_9$ ,<sup>14</sup>  $\text{CuAlO}_2$  (ref. 15) and  $\text{Bi}_2\text{Sr}_2\text{Co}_2\text{O}_x$  (ref. 16) are considered to be promising p-type thermoelectric oxides for high temperature applications. Misfit-layered  $\text{Ca}_3\text{Co}_4\text{O}_9$  (abbreviated as C-349 in the following text) cobaltite is especially an interesting candidate material due to its good thermoelectric performance ( $zT \sim 0.83$  at 973 K for single crystal  $\text{Ca}_3\text{Co}_4\text{O}_9$  and  $\sim 0.64$  at 1073 K for heavily doped polycrystalline  $\text{Ca}_3\text{Co}_4\text{O}_{9+\delta}$  materials with metallic nano-inclusions), and its high thermal and chemical stabilities in air.<sup>17,18</sup>

$\text{Ca}_3\text{Co}_4\text{O}_9$  cobaltite has a monoclinic misfit structure with superspace group  $(X2/m(0b0)s0)$  crystal symmetry. C-349 compound is generally described as  $[\text{Ca}_2\text{CoO}_3][\text{CoO}_2]_{1.61}$  and its high performance is linked with its unique layered crystal structure.<sup>14</sup> It consists of two subsystems: a NaCl-type rocksalt (RS)  $\text{Ca}_2\text{CoO}_3$  layer [subsystem 1] sandwiched between two  $\text{CdI}_2$ -type (H)  $\text{CoO}_2$  hexagonal layers [subsystem 2].<sup>19</sup> These two subsystems share the same  $a$ ,  $c$  and  $\beta$  lattice parameters, and

<sup>a</sup>Department of Chemistry and Chemical Engineering, SBA School of Science and Engineering, Lahore University of Management Sciences (LUMS), Lahore, Pakistan. E-mail: fsher@lums.edu.pk; Tel: +92 42 3560 8131

<sup>b</sup>Department of Energy Conversion and Storage, Technical University of Denmark, Risø DTU, Denmark. E-mail: npr@dtu.dk; Tel: +45 46 775752



stack alternatively along the  $c$  axis. The mismatch of two unit cells results in dissimilar lattice parameters along the  $b$  axis *i.e.*,  $b_1$  [subsystem 1] and  $b_2$  [subsystem 2] with a ratio  $b_1(\text{RS})/b_2(\text{H}) \sim 1.61$ . The  $\text{Ca}_2\text{CoO}_3$  (RS)-type block is an insulating layer whereas  $\text{CoO}_2$  (H) sheet is conductive.<sup>20</sup>

Recently, a number of research studies have focused on improving the TE performance of C-349 polycrystalline materials by using innovative synthesis methods such as spark plasma sintering (SPS),<sup>21</sup> hot pressing,<sup>22</sup> auto-combustion synthesis and sol-gel based electrospinning followed by SPS<sup>23,24</sup> *etc.* Chemical substitution of alternate metal cations at both Ca- and Co-sites of  $\text{Ca}_3\text{Co}_4\text{O}_9$  is another approach that has been used to fine tune the electrical and thermal transport properties of TE oxides. These studies include partial substitution of Na, Bi, Y, Ag, Nd, Sr and Pb ions<sup>25–32</sup> at Ca-sites, which adjusts the carrier concentration without changing much the band structure of materials, and substitution of Fe, Mn, Cu, Ti, Ga, Mo, W and In ions<sup>33–38</sup> at Co-sites with significant changes in the band structure and transport mechanism. In another research work, it was reported that doping of Na ions at Ca-sites resulted in decrease of electrical resistivity and as a consequence increase of thermoelectric power factor to  $\sim 5.5 \times 10^{-4} \text{ W m}^{-1} \text{ K}^{-2}$  at 1000 K, though thermal conductivity ( $\kappa$ ) of these samples was still too high ( $4.0 \text{ W m}^{-1} \text{ K}^{-1}$ ), impeding the further improvement of  $zT$  values.<sup>25</sup> On the other hand, high valence 4d and 5d transition metal-doped C-349 samples exhibited much smaller thermal conductivity with reasonably good  $zT$  values.<sup>39</sup> There are some research studies on simultaneous substitution of two different metal cations at Ca- and Co-sites in C-349 system with significant improvement in TE properties with  $zT$  values of  $\sim 0.20$ – $0.25$ .<sup>40–42</sup> However, there are no reports published on dual doping of Na and W metals in  $\text{Ca}_3\text{Co}_4\text{O}_9$  cobaltite as yet.

This prompted us to prepare a series of  $\text{Ca}_{3-2x}\text{Na}_{2x}\text{Co}_{4-x}\text{W}_x\text{O}_9$  ( $0 \leq x \leq 0.075$ ) oxides by the conventional solid-state reaction method, and investigate their structural and high-temperature thermoelectric properties. We anticipated that Na and W dual doping in C-349 system would increase the Seebeck coefficient and electrical conductivity while thermal conductivity would decrease due to the W substitution. In this way, we expected to achieve much better  $zT$  values for these materials.

## 2. Experimental

Polycrystalline samples of  $\text{Ca}_{3-2x}\text{Na}_{2x}\text{Co}_{4-x}\text{W}_x\text{O}_9$  ( $0 \leq x \leq 0.075$ ) series were prepared by the conventional solid-state reaction method. Stoichiometric quantities of  $\text{CaCO}_3$  ( $\geq 99.5\%$ ; Sigma-Aldrich),  $\text{Co}_3\text{O}_4$  ( $\geq 99.5\%$ ; Sigma-Aldrich) and  $\text{Na}_2\text{WO}_4 \cdot 2\text{H}_2\text{O}$  ( $\geq 99.5\%$ ; Sigma-Aldrich) were ground, thoroughly mixed and pressed into pellets and initially sintered at  $700^\circ\text{C}$  for 8 h. Sintered pellets were reground, pressed into pellets again and sintered twice at  $900^\circ\text{C}$  for 8 h, with intermediate grinding and pelletizing, at a heating rate of  $10^\circ\text{C min}^{-1}$  in air and slowly cooled down to room temperature.

Powder X-ray diffraction (XRD) data were collected in 2 theta range  $5^\circ \leq 2\theta \leq 60^\circ$  with a step size of  $0.02^\circ$  using a Bruker D8 Advanced diffractometer at room temperature with  $\text{Cu K}\alpha$  ( $\lambda = 1.5406 \text{ \AA}$ ) radiation. Rietveld refinements of XRD data were

performed using a computer program JANA2006.<sup>43</sup> Surface morphology of samples was studied using a FEI Nova NanoSEM 450 scanning electron microscope (SEM). X-ray photoelectron spectroscopy (XPS, Thermo Electron Limited, Winsford, UK) was used to examine the oxidation states of Co and W ions in C-349 based materials. Analyses were performed using a monochromatic (Al-K $\alpha$ ) X-ray source at room temperature with a take-off angle of  $90^\circ$  from the surface plane. High-resolution Co 2p and W 4f XPS spectra were recorded using 50 eV detector pass energy and 10 scans. The binding energies were assessed by referencing to the Au 4f peak at 84.0 eV. Hall measurements were carried out at room temperature by using van der Pauw method with a (5.08 T) superconducting magnet.

The Seebeck coefficient ( $S$ ) and electrical resistivity ( $\rho$ ) were simultaneously measured from room temperature to 1000 K with an ULVAC-RIKO ZEM3 under a low pressure helium atmosphere. The thermal diffusivity ( $\alpha$ ) was measured with (NETZSCH LFA-457) laser flash system under vacuum. The heat capacity ( $C_p$ ) was estimated using temperature independent Dulong–Petit law. The thermal conductivity ( $\kappa$ ) was calculated

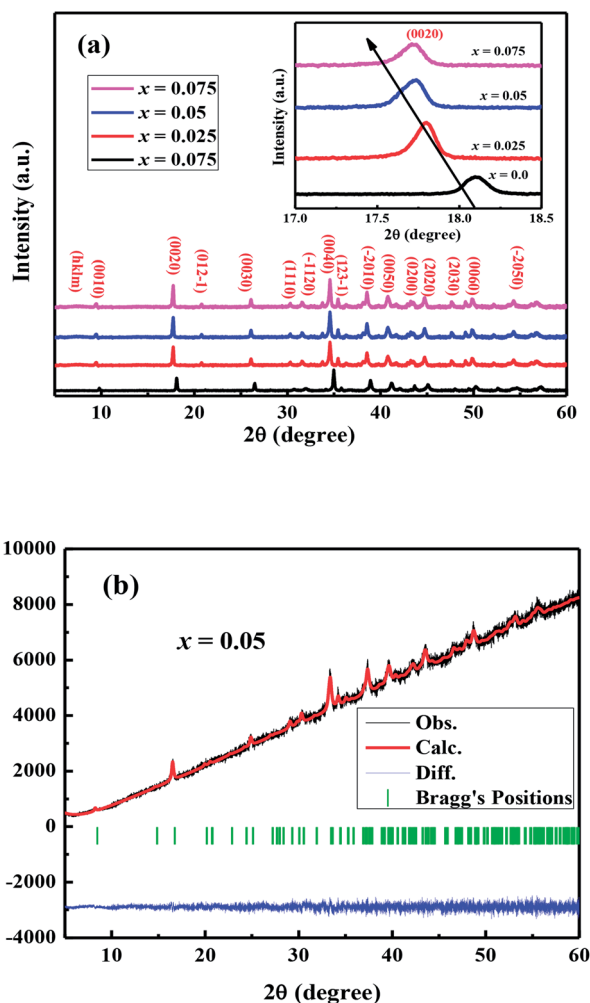


Fig. 1 (a) XRD patterns of  $\text{Ca}_{3-2x}\text{Na}_{2x}\text{Co}_{4-x}\text{W}_x\text{O}_9$  ( $0 \leq x \leq 0.075$ ) samples; inset: the shift of (0020) peaks with change of doping content ( $x$ ). (b) Rietveld refined XRD pattern of  $\text{Ca}_{2.9}\text{Na}_{0.1}\text{Co}_{3.95}\text{W}_{0.05}\text{O}_9$  sample.



**Table 1** Crystallographic parameters for  $\text{Ca}_{3-2x}\text{Na}_{2x}\text{Co}_{4-x}\text{W}_x\text{O}_9$  ( $0 \leq x \leq 0.075$ ) samples obtained from the Rietveld refinement analysis of powder X-ray diffraction data<sup>a</sup>

Composition $\text{Ca}_{3-2x}\text{Na}_{2x}\text{Co}_{4-x}\text{W}_x\text{O}_9$	$x = 0.0$	$x = 0.025$	$x = 0.05$	$x = 0.075$
<b>Lattice parameters</b>				
$a$ (Å)	4.8229(2)	4.8231(5)	4.8268(5)	4.8335(2)
$b_1$ (Å)	4.5453(2)	4.5690(8)	4.5671(9)	4.5689(8)
$b_2$ (Å)	2.8215(3)	2.8134(3)	2.8103(8)	2.8145(3)
$c$ (Å)	10.8215(9)	10.8394(2)	10.8557(2)	10.8498(2)
$\beta$ (deg)	98.807(3)	98.329(1)	98.582(8)	98.396(4)
$\delta$ ( $b_1/b_2$ )	1.61	1.62	1.62	1.62
$V_1$ (Å) <sup>3</sup>	234.7(4)	236.3(4)	236.6(4)	237.0(4)
$V_2$ (Å) <sup>3</sup>	145.2(7)	145.5(7)	145.6(7)	146.0(7)
<b>Reliability factors</b>				
$R_{\text{wp}}$ (%)	3.99	2.94	2.41	1.97
$R_{\text{p}}$ (%)	3.25	2.34	1.93	1.51
GOF	3.29	2.44	1.84	1.97

<sup>a</sup>  $b_1$  and  $b_2$  are the  $b$ -axis lattice parameter for  $[\text{Ca}_2\text{CoO}_3]$  and  $[\text{CoO}_2]$  subsystems, respectively.

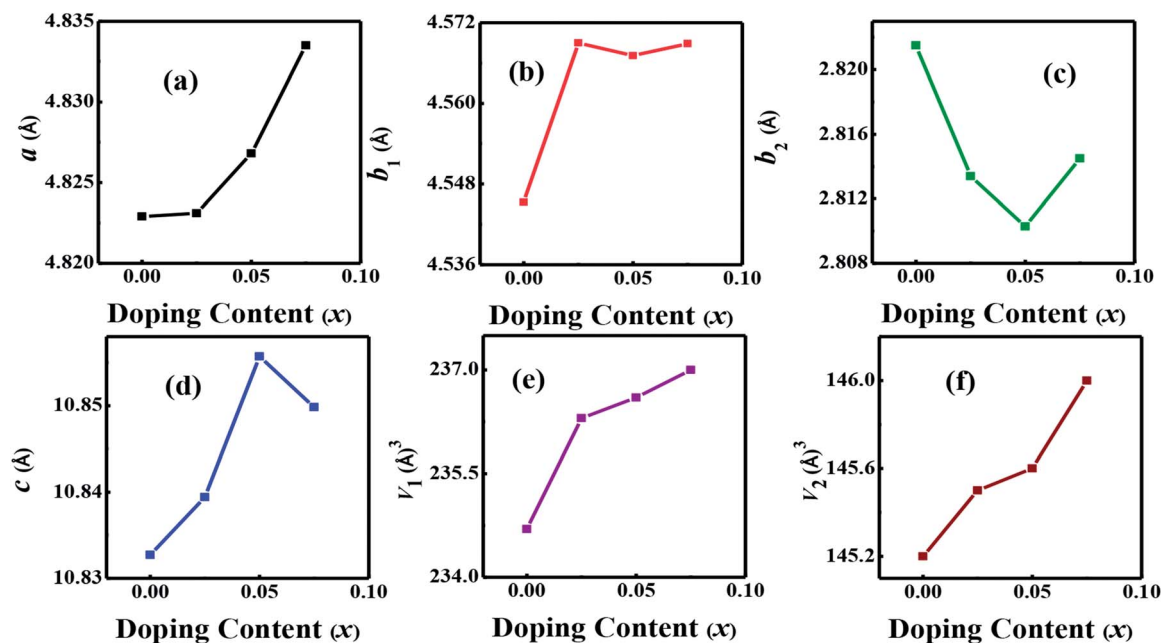
using equation ( $\kappa = \alpha \cdot \rho \cdot C_p$ ), where  $C_p$ ,  $\rho$  and  $\alpha$  are the specific heat capacity, mass density and thermal diffusivity, respectively. Mass density of the samples was measured by Archimedes method using water with a few drops of surfactant.

### 3. Result and discussion

#### 3.1. Crystal structure and surface morphology

The crystal structures of  $\text{Ca}_{3-2x}\text{Na}_{2x}\text{Co}_{4-x}\text{W}_x\text{O}_9$  ( $0 \leq x \leq 0.075$ ) samples were analyzed by collecting the powder X-ray diffraction data at room temperature. The diffraction peaks in XRD patterns of all samples (Fig. 1(a)) are identical to the standard JCPDS card (21-139) of C-349 system,<sup>44</sup> indicating the formation

of phase pure compounds. The enlarged portions of (0020) diffraction peaks are presented in inset of Fig. 1(a) to illustrate the effect of Na and W dual doping on C-349 crystal structure. It can be clearly seen that the diffraction peaks shift to lower  $2\theta$  values with increase in doping content ( $x$ ). The XRD data was Rietveld refined using a computer program JANA 2006 (ref. 43) in the superspace group  $X2/m(0b0)s0$  and the resulting structural parameters are listed in Table 1. The refined XRD pattern of  $x = 0.05$  sample is shown in Fig. 1(b), as an example. It can be seen from Table 1 and Fig. 2 that the lattice parameters  $a$ ,  $b_1$ ,  $c$  and unit cell volumes ( $V_1$  and  $V_2$ ) all slightly increase with increase in doping content ( $x$ ), which is consistent with the observed shifting of diffraction peaks to lower  $2\theta$  values.



**Fig. 2** Structural parameters  $a$ ,  $b_1$ ,  $b_2$ ,  $c$ ,  $V_1$  and  $V_2$  as a function of doping content ( $x$ ) for  $\text{Ca}_{3-2x}\text{Na}_{2x}\text{Co}_{4-x}\text{W}_x\text{O}_9$  ( $0 \leq x \leq 0.075$ ) series.



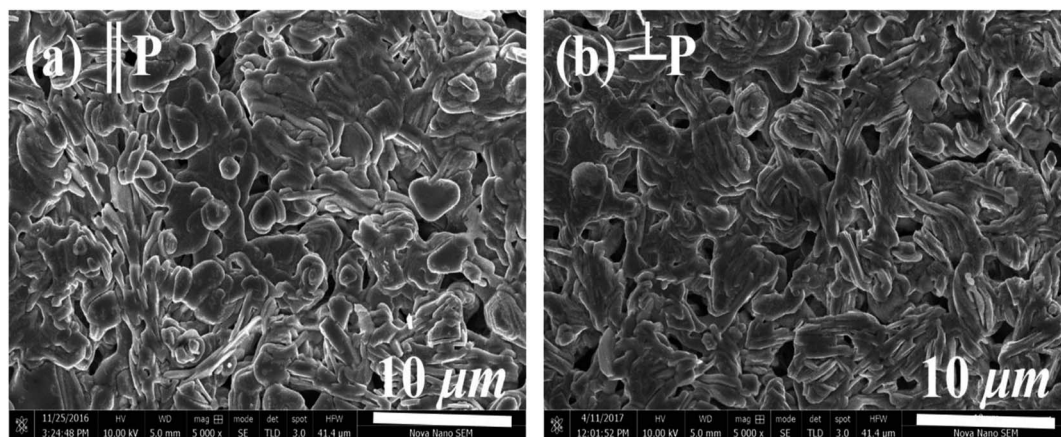


Fig. 3 SEM micrographs of (a) parallel ( $\parallel$ P) and (b) perpendicular ( $\perp$ P) surfaces for  $x = 0.05$  sample.

However, the values of  $b_2$  decrease with increase in doping suggesting that there is an increase of crystallographic distortion. This trend in the lattice parameters with doping is in agreement with the observation that ionic radii of  $\text{Na}^+$  (1.02 Å) and  $\text{W}^{6+}$  (0.6 Å) ions are larger than the corresponding  $\text{Ca}^{2+}$  (1.0 Å) and  $\text{Co}^{3+}$  (0.545 Å)/ $\text{Co}^{4+}$  (0.53 Å) ions in the six coordination number,<sup>45</sup> respectively. The quality factors like GOF,  $R_{\text{wp}}$  and  $R_p$  (Table 1) are all within the acceptable statistical range, suggesting that the Rietveld refinements of samples are reliable.

The morphology of samples in two different directions, parallel ( $\parallel$ p) and perpendicular ( $\perp$ p), to the pellets pressure axis (Fig. 3) were studied by the scanning electron microscopy in order to find out if there is any micro-dimensional anisotropy in these layered materials. The grain morphology in both parallel ( $\parallel$ p) and perpendicular ( $\perp$ p) directions of the pressure axis seems to be almost identical, suggesting that there is no or negligible anisotropy that can be observed on a micrometer scale. The SEM images show the plate-like crystal grains morphology, which is a typical feature of materials, including C-349 system, that are prepared by the conventional solid state chemistry method.<sup>46</sup> Close inspection of the SEM micrograph for  $x = 0.025$  sample reveals that crystal grains are larger ( $\sim 2.52 \mu\text{m}$ ) and more compact than crystal grains of other samples (0.83–1.45  $\mu\text{m}$ ). The measured densities for all samples are in the range  $\sim 86$ –94% of the theoretical density (Table 2).

The binding energies of Co 2p and W 4f sub-shells of selected samples were estimated from the high resolution XPS measurements as shown in Fig. 4. As reported elsewhere, the XPS spectrum of Co 2p splits into two parts, Co 2p<sub>3/2</sub> and 2p<sub>1/2</sub> with an intensity ratio of approximately (2 : 1) due to the spin-orbit coupling.<sup>47</sup> The line shapes of both Co 2p<sub>3/2</sub> and 2p<sub>1/2</sub> spectra are similar to the reported results in literature.<sup>48</sup> The main peaks corresponding to the Co 2p<sub>3/2</sub> energy are located at 778.8 eV, 779.69 eV and 781.0 eV corresponding to  $x = 0.0$ , 0.025 and 0.075 samples, respectively. Shake-up satellite peaks due to the metal-to-ligand charge transfer processes at higher binding energies than the 2p<sub>3/2</sub> and 2p<sub>1/2</sub> main peaks are also detected. The observed variations in Co 2p<sub>3/2</sub> binding energies can be explained by the larger electronegativity of tungsten (2.36, Pauli scale) than cobalt (1.88, Pauli scale).<sup>49</sup> With careful analysis of XPS data, we can predict that Co ions have three types of valence states:  $\text{Co}^{2+}$ ,  $\text{Co}^{3+}$  and  $\text{Co}^{4+}$  in all samples. However, the average valence state of Co is most likely between 3+ and 4+ as reported elsewhere.<sup>50,51</sup> The observed increase in binding energies of Co 2p<sub>3/2</sub> peaks suggests that the relative population of  $\text{Co}^{3+}$  ions is decreasing with increase in doping. The 4f<sub>5</sub> and 4f<sub>7</sub> peaks for W ions closely resemble with the reference peaks of  $\text{WO}_3$ , indicating that they are present in  $\text{W}^{6+}$  valence states in all samples.

Table 2 Average grain size, bulk density, carrier mobility ( $\mu_{300 \text{ K}}$ ), activation energy ( $E_a$ ) and important thermoelectric parameters are listed

Composition $\text{Ca}_{3-2x}\text{Na}_{2x}\text{Co}_{4-x}\text{W}_x\text{O}_9$	$x = 0.0$	$x = 0.025$	$x = 0.05$	$x = 0.075$
Average grain size ( $\mu\text{m}$ )	0.83 ( $\pm 0.002$ )	2.52 ( $\pm 0.09$ )	1.45 ( $\pm 0.005$ )	0.80 ( $\pm 0.007$ )
Density ( $\text{g cm}^{-3}$ )	3.801 ( $\pm 0.02$ )	4.09 (0.045)	3.98 ( $\pm 0.032$ )	3.844 ( $\pm 0.068$ )
Theoretical density ( $\text{g cm}^{-3}$ )	4.37	4.37	4.38	4.39
Relative density (%)	86.27	94.67	90.87	87.56
Mobility, $\mu_{300 \text{ K}}$ ( $\text{cm}^2 \text{V}^{-1} \text{s}^{-1}$ )	0.64	0.82	0.74	0.65
$\rho_{T=1000 \text{ K}} \times 10^{-5}$ ( $\Omega\text{m}$ )	23.98	13.07	16.09	27.54
$E_a$ (meV)	49	98	103	76
$S_{T=1000 \text{ K}}$ ( $\mu\text{V K}^{-1}$ )	174.99	182.72	192.67	215.99
$\kappa_{T=1000 \text{ K}}$ ( $\text{W m}^{-1} \text{K}^{-1}$ )	1.367	1.266	1.323	1.343
$zT_{T=1000 \text{ K}}$	0.093	0.21	0.18	0.13



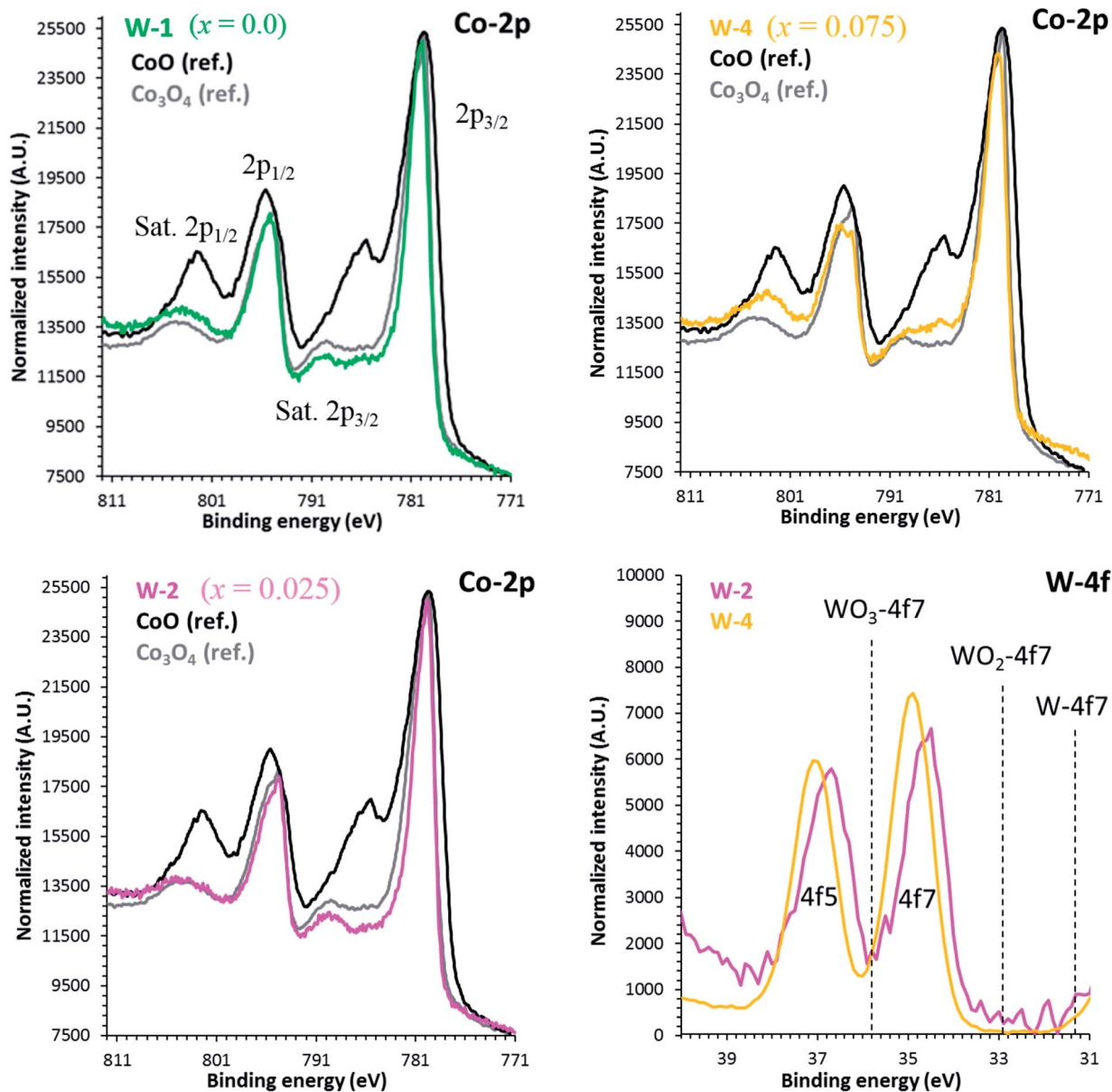


Fig. 4 High resolution XPS spectra of Co 2p and W 4f for C-349 doped samples. Reference positions are taken from the NIST database.

### 3.2. Thermoelectric properties

The temperature dependent electrical resistivities,  $\rho(T)$ , as a function of Na and W co-doping ( $x$ ) are shown in Fig. 5(a). The  $\rho(T)$  curve for  $x = 0.0$  sample exhibits a semiconducting like behavior ( $d\rho/dT < 0$ ) from room temperature to around 500 K, and then shows a transition to metallic like behavior ( $d\rho/dT > 0$ ) from 600 K onwards. This kind of behavior in resistivity of C-349 system has been previously attributed to the spin-state transition,<sup>52</sup> removal of oxygen atoms from porous layered cobaltites<sup>38</sup> and structural distortion in  $\text{Ca}_2\text{CoO}_3$  sheets.<sup>53</sup> On the other hand, all doped samples show metallic behavior at low temperatures before showing a transition to semiconducting behavior above 400 K. The absolute values of resistivity at 1000 K for  $x = 0.025$  and  $0.05$  samples are smaller than that of undoped sample, but higher for  $x = 0.075$ . This shows that dual

doping of small amounts of Na and W has beneficial effect on resistivity of our samples.

We can describe the high temperature electrical resistivity of cobaltites using the small polaron hopping model,<sup>54</sup> which is given by the following relation:

$$\rho(T) = \rho_0 T \exp\left(\frac{E_a}{k_B T}\right) \quad (2)$$

where  $\rho_0$  is a constant factor called the residual resistivity,  $k_B$  is the Boltzmann constant and  $E_a$  is the activation energy of electrical conductivity for polaron hopping.

The linear fits of  $\ln(\rho/T)$  versus  $1/T$  above 600 K, as shown in Fig. 5(b), suggest that the small polaron hopping model applies well to the electrical resistivity of these materials. The slopes of straight lines ( $E_a/k_B$ ) were used to estimate the activation



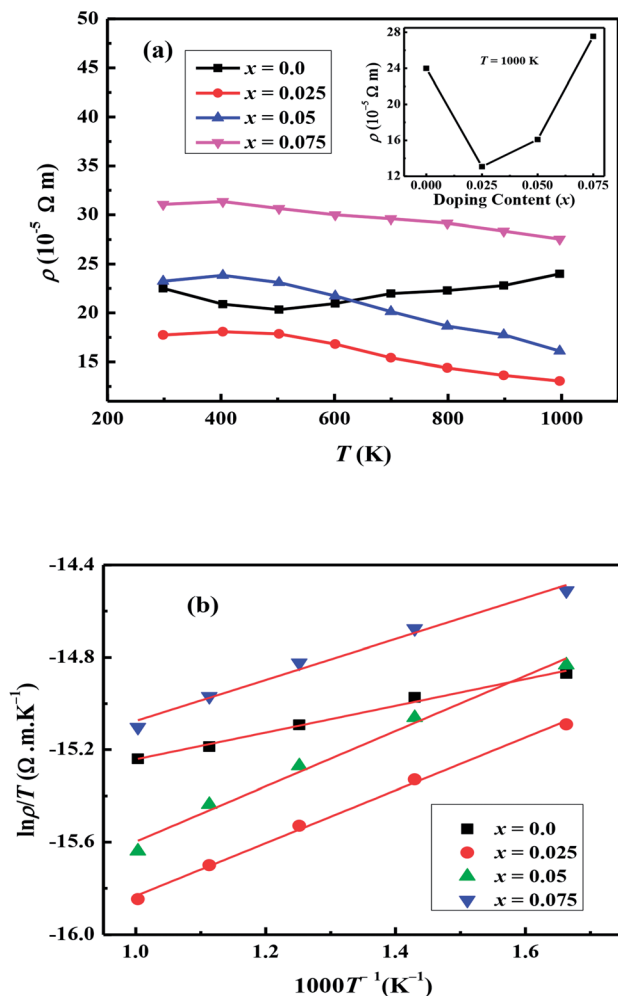


Fig. 5 (a) Electrical resistivity ( $\rho$ ) for  $\text{Ca}_{3-2x}\text{Na}_{2x}\text{Co}_{4-x}\text{W}_x\text{O}_9$  ( $0 \leq x \leq 0.075$ ) samples as a function of temperature; inset shows doping content ( $x$ ) dependence of  $\rho$  at 1000 K. (b) Linear fits of  $\ln(\rho/T)$  vs.  $1000/T$  for  $\text{Ca}_{3-2x}\text{Na}_{2x}\text{Co}_{4-x}\text{W}_x\text{O}_9$  ( $0 \leq x \leq 0.075$ ) samples.

energies for all samples as listed in Table 2. It has been observed that  $E_a$  values for doped samples are relatively higher than the pristine C-349 system. This suggests that energy demand for carriers to jump from the top of valence band to the bottom of conduction band, in general, increases with doping in our samples. However, this variation could also be due to the creation of some in-gap states which would change with doping. As discussed elsewhere, hopping of carriers occurs between  $\text{Co}^{3+}$  and  $\text{Co}^{4+}$  in  $\text{CoO}_2$  layer and as a consequent the ratio of  $\text{Co}^{3+}$  and  $\text{Co}^{4+}$  ions directly affects the hopping distance in these materials.<sup>55</sup> We anticipate that concentration of  $\text{Co}^{4+}$  ions would decrease with increase in doping of  $\text{W}^{6+}$  ions resulting in increase of hopping distance and therefore increase in activation energies with doping. Similar results have been reported for the activation energies of Fe, Ag, Gd and Y doped misfit layered cobaltites.<sup>41,55,56</sup>

Hall effect measurements were carried out at room temperature for all samples, to determine the carrier concentration and their mobility as a function of dopant. It has been observed that carrier concentration ( $n_{300\text{ K}}$ ) initially increases from  $5.12 \times 10^{19} \text{ cm}^{-3}$  ( $x = 0.0$ ) to  $6.59 \times 10^{19} \text{ cm}^{-3}$  ( $x = 0.025$ ) with doping

and then decreases again to  $4.48 \times 10^{19} \text{ cm}^{-3}$  ( $x = 0.075$ ) with further increase in doping content as shown in Fig. 6. This increase in carrier concentration at low doping level is probably due to the substitution of  $\text{Na}^+$  for  $\text{Ca}^{2+}$  ions in C-349 system which results in increase of the number of hole carriers. With further increase in doping content ( $x$ ), structural distortions and electron-doping like behavior of  $\text{W}^{6+}$  ions, due to the higher valence state of  $\text{W}^{6+}$  than  $\text{Co}^{3+}$  and  $\text{Co}^{4+}$  ions, start to dominate and result in decrease of carrier concentration. The carrier mobilities ( $\mu_{300\text{ K}}$ ) also follow the same trend and decrease to a value of  $0.65 \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$  with increase in doping after showing the maximum value for  $x = 0.025$  sample (Table 2). These trends in  $n_{300\text{ K}}$  and  $\mu_{300\text{ K}}$  together with the larger grain sizes (Table 2) of Na and W dual doped samples can be used to explain the electrical resistivity of these materials. With the largest values of  $n_{300\text{ K}}$ ,  $\mu_{300\text{ K}}$  and grain sizes, the  $x = 0.025$  sample has the lowest value of electrical resistivity and then  $\rho$  increases with increase in doping according to the equation:  $1/\rho = ne\mu$ .

Fig. 7(a) shows the temperature dependence of thermopower ( $S$ ) of the  $\text{Ca}_{3-2x}\text{Na}_{2x}\text{Co}_{4-x}\text{W}_x\text{O}_9$  samples. The sign of  $S$  is positive for all samples suggesting that holes are the majority charge carriers. The values of  $S$  increase with increase in temperature for all samples. It is also evident from Fig. 7(a) (inset) that thermopower values increase with increase in doping content ( $x$ ). The maximum value of  $216 \mu\text{V K}^{-1}$  at 1000 K for  $x = 0.075$  sample is higher than previously reported  $S$  values for Na doped C-349 system ( $187 \mu\text{V K}^{-1}$ ) at this temperature.<sup>25,40</sup> As discussed above,  $x = 0.025$  sample shows the largest values of  $n_{300\text{ K}}$  and  $\mu_{300\text{ K}}$ , and then values of these quantities decrease with further increase in doping. This is consistent with the observed behavior of  $S$  with doping in our samples.<sup>26,28</sup> The contribution of carrier concentration and carrier mobility,  $\mu(\varepsilon)$  in describing  $S$  is given by the Mott's formula (originated from the Sommerfeld expansion).<sup>57</sup>

$$S(T) = \frac{\pi^2 k_B^2 T}{3e} \left[ \frac{\partial (\ln(\sigma(\varepsilon)))}{\partial \varepsilon} \right]_{\varepsilon=\varepsilon_F} \quad (3)$$

By using  $[\sigma = en\mu(\varepsilon)]$  in eqn (3), we can get:

$$S(T) = \frac{C_e}{n} + \frac{\pi^2 k_B^2 T}{3e} \left[ \frac{\partial \ln \mu(\varepsilon)}{\partial \varepsilon} \right]_{\varepsilon=\varepsilon_F} \quad (4)$$

where  $C_e = (\pi^2 k_B^2 T/3e)\Psi(\varepsilon)$  and  $n$ ,  $\mu(\varepsilon)$ ,  $C_e$  and  $\Psi(\varepsilon)$  are the carrier concentration, energy correlated carrier mobility, electronic specific heat and density of state (DOS), respectively. There are three possible reasons associated with this increase in  $S$  values: (1) the Drude model predicts that first term  $\left(\frac{C_e}{n}\right)$  in above equation is dominant.<sup>58</sup> In Na and W dual doped samples, carrier concentration ( $n$ ) decreases with increase in doping ( $x$ ) and therefore thermopower ( $S$ ) increases. However,  $x = 0.0$  sample does not follow this trend suggesting that the electronic specific heat ( $C_e$ ) and second term in above equation are the dominated factors here. Wang *et al.*, reported that Fe doping in C-349 system increases the carrier concentration ( $n$ )



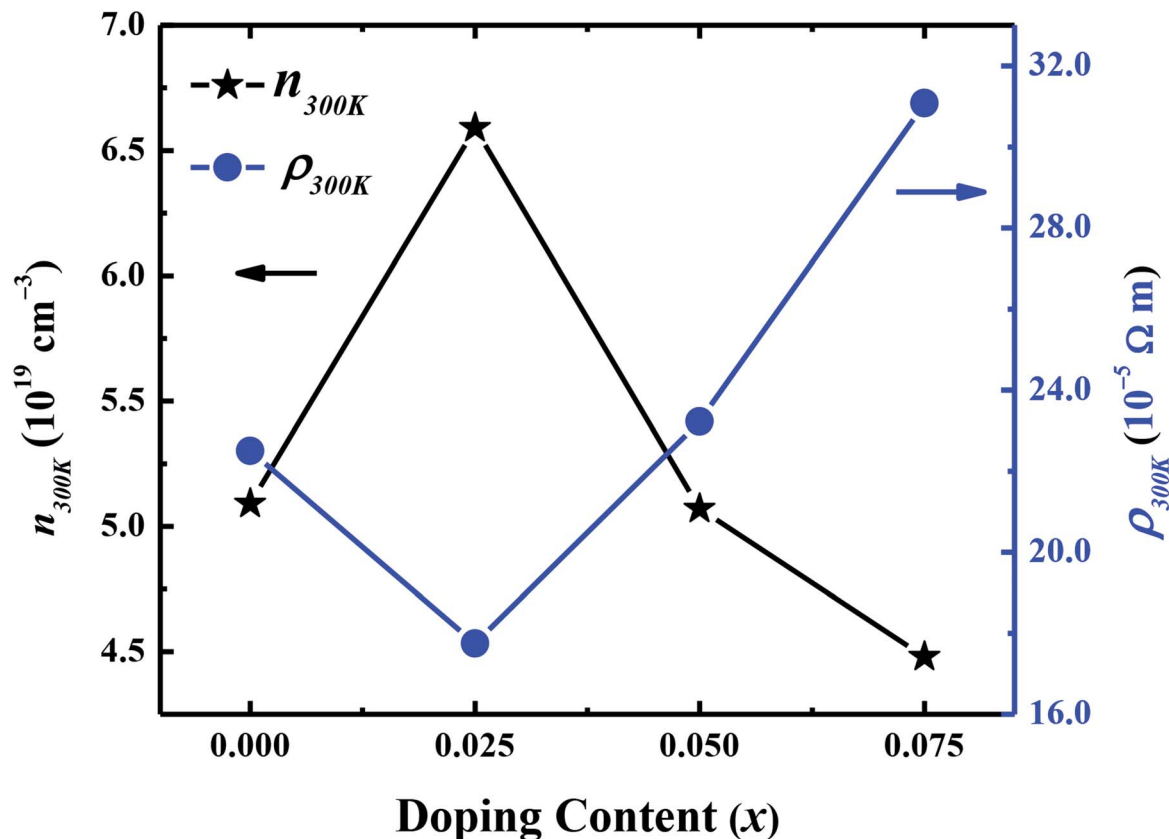


Fig. 6 Room temperature carrier concentration ( $n_{300K}$ ) and electrical resistivity ( $\rho_{300K}$ ) as a function of doping ( $x$ ) for  $\text{Ca}_{3-2x}\text{Na}_{2x}\text{Co}_{4-x}\text{W}_x\text{O}_9$  ( $0 \leq x \leq 0.075$ ) samples.

and the electronic specific heat ( $C_e$ ), but the effect of  $C_e$  dominates over  $n$  which results in larger  $S$  values for doped samples.<sup>59</sup> (2) We could assume that slope of the density of states at Fermi level is the main contribution to the second part of the above equation for undoped sample. (3) Partial substitution of  $\text{W}^{6+}$  for  $\text{Co}^{3+}/\text{Co}^{4+}$  ions decreases hole carriers and thus results in an increase of thermopower.

According to the Pisarenko relation for degenerated semiconductors:

$$|S| = \frac{8\pi^2 k_B^2 T}{3qh^2} m^* \left( \frac{\pi}{3n} \right)^{2/3} \quad (5)$$

where  $k_B$ ,  $h$ ,  $q$  and  $m^*$  are the Boltzmann constant, Planck's constant, unit charge of electron and effective mass of carriers respectively. We have calculated a value of  $m^*/m_e \sim 0.9$  for all samples by plotting room temperature  $S$  values vs.  $n^{-2/3}$  as shown in inset of Fig. 5(b). We can apply a simple parabolic band model by using the measured  $n$  and estimated  $m^*$  values as described by the following equations:<sup>60</sup>

$$F_{1/2}(\xi) = \int_0^\infty \frac{x^2 dx}{1 + \exp(x - \xi)} \quad (6)$$

$$S = -\frac{k_B}{q} \left[ \frac{(2 + \lambda)F_\lambda + 1}{(1 + \lambda)F_\lambda} - \xi \right] \quad (7)$$

$$n = 4\pi \left( \frac{2m^*k_B T}{h^2} \right)^{2/3} F_{1/2} \quad (8)$$

where  $F_{1/2}(\xi)$  is the Fermi integral,  $\xi$  is the reduced electrochemical potential,  $\lambda$  is a scattering parameter and its value is taken 0 for acoustic phonon scattering, 1 for optical phonons scattering, and 2 for ionized impurity scattering.<sup>60</sup> The calculated  $S$  values at room temperature as a function of carrier concentration ( $n$ ) are shown in Fig. 7(b). Three different scattering mechanisms are represented by three straight lines in this plot. The measured and calculated values of  $S$  match very well when we take  $\lambda = 0$ , which suggests that the acoustic phonon scattering is the dominant scattering mechanism for all samples.

We have used the electrical resistivity and thermopower values to calculate the thermoelectric power factor  $\text{PF} = S^2/\rho$  for all samples as shown in Fig. 8. The PF values increase with increase in temperature for all samples due to increase of thermopower with temperature. We can also see from Fig. 8 that PF values are significantly improved with Na and W dual doping in C-349 system. Among all doped samples,  $x = 0.025$  sample exhibits the highest PF of  $2.71 \times 10^{-4} \text{ W m}^{-1} \text{ K}^{-2}$  at 1000 K which is about 2.3 times more than PF,  $1.27 \times 10^{-4} \text{ W m}^{-1} \text{ K}^{-2}$ , of undoped sample. The PF obtained in this work is higher than the previously reported value of  $\sim 2.1 \times 10^{-4} \text{ W m}^{-1} \text{ K}^{-2}$  at 1073



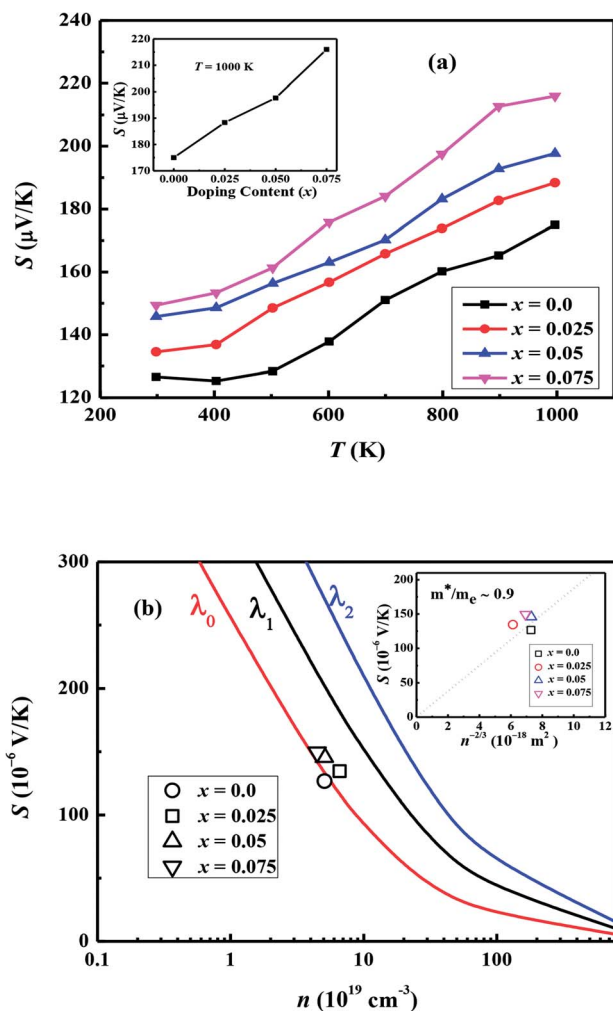


Fig. 7 (a) Thermopower ( $S$ ) for  $\text{Ca}_{3-2x}\text{Na}_{2x}\text{Cu}_{4-x}\text{W}_x\text{O}_9$  ( $0 \leq x \leq 0.075$ ) samples as a function of temperature; inset shows doping content ( $x$ ) dependence of  $S$  at 1000 K. (b) Thermopower ( $S$ ) plotted as a function of carrier concentration ( $n$ ); solid colored lines are the calculated values for ( $\lambda = 0, 1 \& 2$ ) representing electron scattering by acoustic phonons, optical phonons and ionized impurities respectively. Inset: plot of  $S$  vs.  $(n^{-2/3})$ ; diagonal line corresponding to the Pisarenko relation with  $m^*/m_e \sim 0.9$ .

K for  $\text{Ca}_3\text{Co}_{3.97}\text{Cu}_{0.03}\text{O}_9$  sample prepared by the conventional solid state reaction method.<sup>61</sup>

**3.2.1. Thermal conductivity.** The temperature dependent total thermal conductivity ( $\kappa_{\text{Total}}$ ) for  $\text{Ca}_{3-2x}\text{Na}_{2x}\text{Cu}_{4-x}\text{W}_x\text{O}_9$  samples is shown in Fig. 9(a). We can clearly see that  $\kappa(T)$  decreases with increase in temperature for all samples in the measured temperature range. For  $x = 0.0$  sample, measured value of  $\kappa$  at 1000 K is  $1.36 \text{ W m}^{-1} \text{ K}^{-1}$  and it decreases to  $1.26 \text{ W m}^{-1} \text{ K}^{-1}$  for  $x = 0.025$  sample. On further increase in doping,  $\kappa_{1000 \text{ K}}$  slightly increases again but its value remains lower than the pristine C-349 system. In order to understand the observed changes, we have investigated the contribution of electronic ( $\kappa_{\text{el}}$ ) and lattice ( $\kappa_{\text{Lattice}}$ ) parts of the thermal conductivity, separately. Fig. 9(b) shows the values of  $\kappa_{\text{el}}$  as determined from the experimentally measured  $\rho$  values by using the

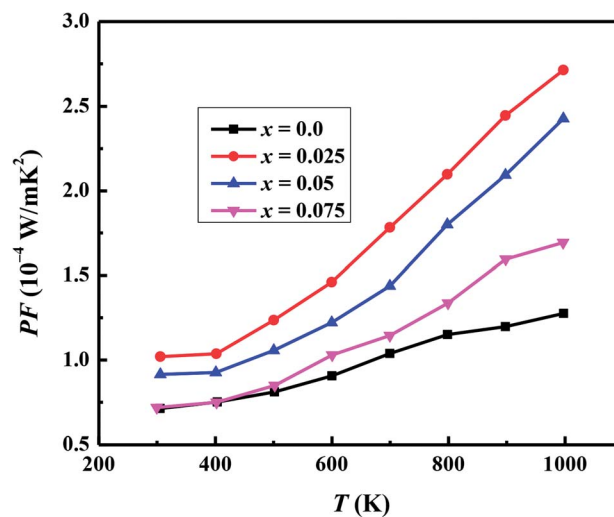


Fig. 8 Power factor (PF) for  $\text{Ca}_{3-2x}\text{Na}_{2x}\text{Cu}_{4-x}\text{W}_x\text{O}_9$  ( $0 \leq x \leq 0.075$ ) samples as a function of temperature.

Wiedemann–Franz law ( $\kappa_{\text{el}} = LT/\rho$ ), where  $L$  is the Lorentz number and its value is  $2.44 \times 10^{-8} \text{ W } \Omega \text{ K}^{-2}$  for free electrons.<sup>3</sup> The values of  $\kappa_{\text{Lattice}}$  were calculated using the relation  $\kappa_{\text{Lattice}} = \kappa_{\text{Total}} - \kappa_{\text{el}}$  and are shown in Fig. 9(c). It is evident from plot that  $\kappa_{\text{Lattice}}$ , and not  $\kappa_{\text{el}}$ , is the major contributing factor to total thermal conductivity of our samples. Hence, changes in  $\kappa_{\text{Total}}$  with increase in doping content ( $x$ ) are mainly originated from the changes in  $\kappa_{\text{Lattice}}$ .<sup>33</sup> We can attribute these changes in  $\kappa_{\text{Lattice}}$  to the larger ionic radius of  $\text{W}^{6+}$  than  $\text{Co}^{3+}/\text{Co}^{4+}$  ions resulting in structural distortions, and therefore increase in phonon scattering. However, we cannot rule out some other unexplained microstructural aspects of these materials that can also be responsible for irregular behavior in thermal conductivity of doped samples.

**3.2.2. Figure of merit.** The thermoelectric figure of merit ( $zT = S^2/\kappa\rho$ ) for  $\text{Ca}_{3-2x}\text{Na}_{2x}\text{Cu}_{4-x}\text{W}_x\text{O}_9$  samples as a function of temperature and doping content ( $x$ ) are shown in Fig. 10. It is evident that  $zT$  values of doped samples are significantly higher than the pristine C-349 system. The  $x = 0.025$  has the highest  $zT$  value of 0.21 at 1000 K among all samples, which is about 2.3 times higher than  $zT$  value of the undoped sample. This increase in  $zT$  value is due to increase in Seebeck coefficient, and decrease in electrical resistivity and thermal conductivity of this sample.  $zT$  values of other doped samples are also reasonably good as listed in Table 2. As a comparison,  $zT$  value of our  $x = 0.025$  sample is comparable or slightly better than previously reported results of Na doped  $\text{Ca}_{2.5}\text{Na}_{0.5}\text{Co}_4\text{O}_9$  ( $zT_{1000 \text{ K}} = 0.18$ ),<sup>25</sup> Bi and Na dual doped C-349 system ( $zT_{1073 \text{ K}} = 0.18$ ),<sup>62</sup>  $\text{Ca}_{2.8}\text{La}_{0.2}\text{Co}_{3.8}\text{Cu}_{0.2}\text{O}_9$  ( $zT_{773 \text{ K}} = 0.203$ ),<sup>40</sup> Bi and Na substituted  $\text{Ca}_3\text{Co}_4\text{O}_9$  system ( $zT_{1000 \text{ K}} = 0.32$ ),<sup>26</sup> Gd and Y dual doped  $\text{Ca}_{2.7}\text{Gd}_{0.15}\text{Y}_{0.15}\text{Co}_4\text{O}_{9+\delta}$  ( $zT_{973 \text{ K}} = 0.26$ ),<sup>63</sup> NaF doped  $\text{Ca}_{3-x}\text{Na}_x\text{Co}_4\text{O}_{9-x}\text{F}_x$  ( $zT_{873 \text{ K}} = 0.13$ )<sup>64</sup> and  $\text{Ca}_{2.9}\text{Y}_{0.1}\text{Co}_{3.97}\text{Fe}_{0.03}\text{O}_9$  ( $zT_{1000 \text{ K}} = 0.22$ ) compound.<sup>42</sup> It has been observed that electrical resistivity of our samples is still higher than most of the previously reported results, and therefore  $zT$  values of these materials are moderate. We believe





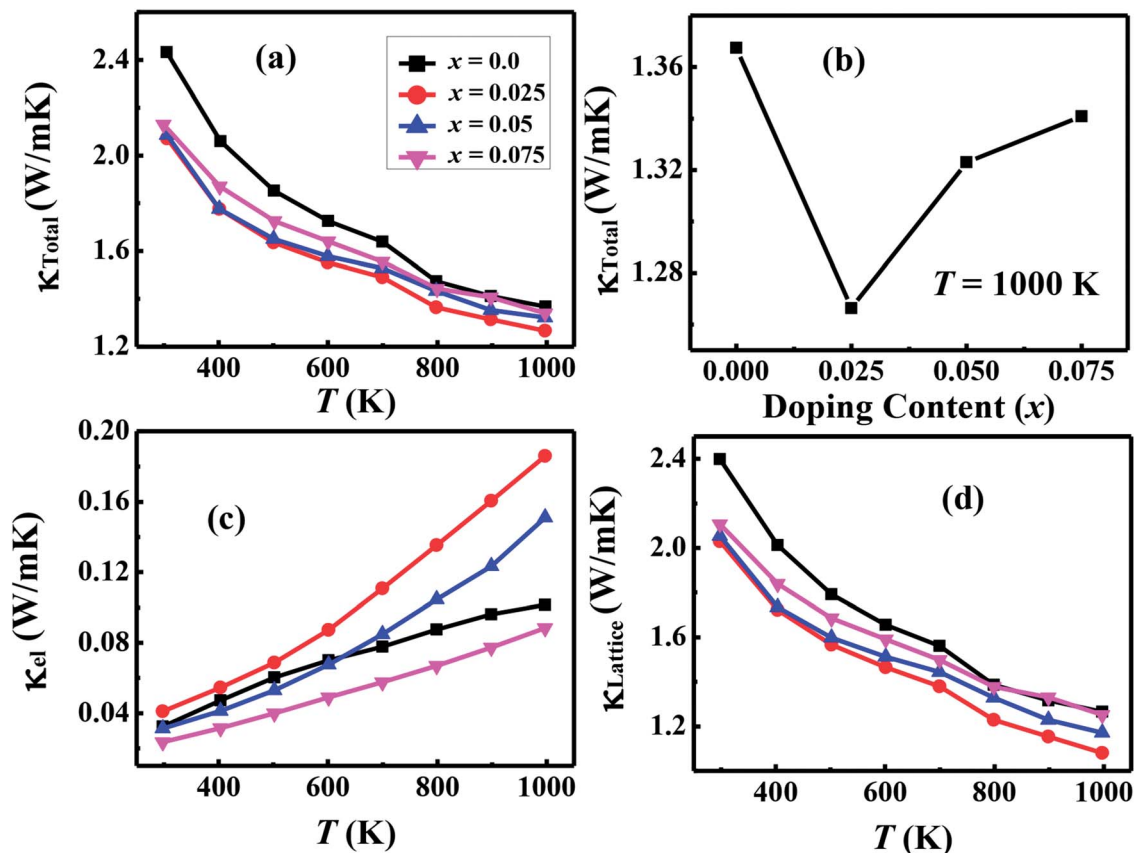


Fig. 9 (a) Total thermal conductivity ( $\kappa_{\text{Total}} = \kappa_{\text{el}} + \kappa_{\text{Lattice}}$ ); (b) doping content ( $x$ ) dependence of  $\kappa_{\text{Total}}$  at 1000 K; (c) electronic part of thermal conductivity ( $\kappa_{\text{el}}$ ) and (d) lattice part of thermal conductivity ( $\kappa_{\text{Lattice}}$ ) for  $\text{Ca}_{3-2x}\text{Na}_{2x}\text{Co}_{4-x}\text{W}_x\text{O}_9$  ( $0 \leq x \leq 0.075$ ) samples as a function of temperature.

that  $zT$  values of these samples can be further improved by preparing more compact materials under optimized synthesis conditions.

## 4. Conclusion

Polycrystalline samples of  $\text{Ca}_{3-2x}\text{Na}_{2x}\text{Co}_{4-x}\text{W}_x\text{O}_9$  ( $0 \leq x \leq 0.075$ ) have been synthesized by the conventional solid state reaction method. Powder X-ray diffraction data revealed that  $\text{Na}^+$  and  $\text{W}^{6+}$  ions enter into the  $\text{Ca}_2\text{CoO}_3$  and  $\text{CoO}_2$  layers of  $\text{Ca}_3\text{Co}_4\text{O}_9$  system respectively. High resolution XPS data showed that the average valence state of Co in our samples is between 3+ and 4+. Significant improvements in  $\rho$ ,  $S$  and  $\kappa$  values of Na and W dual doped samples have been observed. These results are also supported by the carrier concentrations ( $n$ ) and carrier mobility ( $\mu$ ) as confirmed by the Hall effect measurements. The observed power factor (PF) and thermoelectric figure of merit ( $zT$ ) of  $2.71 \times 10^{-4} \text{ W m}^{-1} \text{ K}^{-2}$  and 0.21 respectively at 1000 K for  $x = 0.025$  sample are comparable or slightly higher than most of the reported results of C-349 based materials, prepared by the conventional solid state reaction method. These results show that Na and W dual doping is an effective route for improving thermoelectric properties of  $\text{Ca}_3\text{Co}_4\text{O}_9$  system.

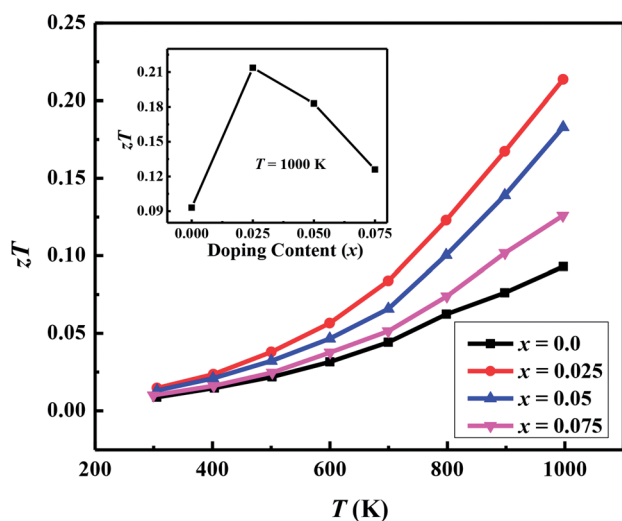


Fig. 10 Thermoelectric figure of merit ( $zT$ ) for  $\text{Ca}_{3-2x}\text{Na}_{2x}\text{Co}_{4-x}\text{W}_x\text{O}_9$  ( $0 \leq x \leq 0.075$ ) samples as a function of temperature; inset shows doping content ( $x$ ) dependence of  $zT$  at 1000 K.

## Conflicts of interest

There are no conflicts to declare.



## Acknowledgements

We are thankful to the Higher Education Commission (HEC) of Pakistan (Grant no. 1981), and the International Research Support Initiative Program of HEC for providing financial support to us. UH is grateful to the Department of Energy Conversion and Storage, Technical University of Denmark (DTU) for the support.

## References

- 1 L. E. Bell, *Science*, 2008, **321**, 1457.
- 2 T. Wu, T. A. Tyson, J. Bai, K. Pandya, C. Jaye and D. Fischer, *J. Mater. Chem. C*, 2013, **1**, 4114–4121.
- 3 G. J. Snyder and E. S. Toberer, *Nat. Mater.*, 2008, **7**, 105.
- 4 D. M. Rowe, *Thermoelectrics Handbook – Macro to Nano*, CRC Press, Taylor & Francis Group, Boca Raton, Florida, 2006.
- 5 G. J. Snyder, E. Christensen, E. Nishibori, T. Gaillat and B. B. Iversen, *Nat. Mater.*, 2004, **3**, 458.
- 6 X. B. Zhao, X. H. Ji, Y. H. Zhang, T. J. Zhu, J. P. Tu and X. B. Zhang, *Appl. Phys. Lett.*, 2005, **86**, 062111.
- 7 D. Zhao, C. Tian, S. Tang, Y. Liu and L. Chen, *J. Alloys Compd.*, 2010, **504**, 552.
- 8 L. Han, N. V. Nong, W. Zhang, L. T. Hung, T. Holagate, K. Tashiro, M. Ohtaki, N. Pryds and S. Linderoth, *RSC Adv.*, 2014, **4**, 12353.
- 9 A. A. Yaremchenko, S. Populoh, S. G. Patricio, J. Macias, P. Thiel, D. P. Fagg, A. Weidenkaff, J. R. Frade and A. V. Kovalevsky, *Chem. Mater.*, 2015, **27**, 4995.
- 10 J. W. Fergus, *J. Eur. Ceram. Soc.*, 2012, **32**, 525.
- 11 P. H. Ngan, D. V. Christensen, G. J. Snyder, L. T. Hung, S. Linderoth, N. V. Nong and N. Pryds, *Phys. Status Solidi A*, 2014, **211**, 9.
- 12 X. Liu, Y. D. Deng, Z. Li and C. Q. Su, *Energy Convers. Manage.*, 2015, **90**, 121.
- 13 Y. Terasaki, K. Sasago and K. Uchinokura, *Phys. Rev. B: Condens. Matter*, 1997, **56**, R12685.
- 14 A. C. Masset, C. Michel, A. Maignan, M. Hervieu, O. Toulemonde, F. Studer, B. Raveau and J. Hejtmanek, *Phys. Rev. B: Condens. Matter*, 2000, **62**, 166.
- 15 S. Yanagiya, N. V. Nong, X. Jianxiao and N. Pryds, *Materials*, 2010, **3**, 318.
- 16 F. Funahashi, I. Matsubara and S. Sodeoka, *Appl. Phys. Lett.*, 2000, **76**, 2385.
- 17 M. Shikano and R. Funahashi, *Appl. Phys. Lett.*, 2003, **82**, 1851.
- 18 N. V. Nong, N. Pryds, S. Linderoth and M. Ohtaki, *Adv. Mater.*, 2011, **23**, 2484.
- 19 D. Grebille, S. Lambert, F. Bouree and V. Petricek, *J. Appl. Crystallogr.*, 2004, **37**, 823.
- 20 G. Yang, Q. Ramasse and R. F. Klie, *Phys. Rev. B: Condens. Matter Mater. Phys.*, 2008, **78**, 153109.
- 21 J. G. Noudem, D. Kenfaui, D. Chateigner and M. Gomina, *J. Electron. Mater.*, 2011, **40**, 1100.
- 22 V. Garnier, R. Caillard, A. Sotelo and G. Desgardin, *Phys. C*, 1999, **319**, 197.
- 23 N. Y. Wu, T. C. Holgate, N. V. Nong, N. Pryds and S. Linderoth, *J. Eur. Ceram. Soc.*, 2014, **34**, 925.
- 24 T. Yin, D. Liu, Y. Ou, F. Ma, S. Xie, J.-F. Li and J. Li, *J. Phys. Chem. C*, 2010, **114**, 10061.
- 25 G. Xu, R. Funahashi, M. Shikano, Q. Pu and B. Liu, *Solid State Commun.*, 2002, **124**, 73.
- 26 G. Xu, R. Funahashi, M. Shikano, I. Matsubara and Y. Zhou, *Appl. Phys. Lett.*, 2002, **80**, 3760.
- 27 Y. Song, Q. Sun, L. Zhao and F. Wang, *Key Eng. Mater.*, 2010, **434**, 393.
- 28 Y. Wang, Y. Sui, J. G. Cheng, X. J. Wang, W. H. Su, X. Y. Liu and H. J. Fan, *J. Phys. Chem. C*, 2010, **114**, 5174.
- 29 Y. Wang, Y. Sui, J. Cheng, X. Wang, J. Miao, Z. Liu, Z. Qian and W. Su, *J. Alloys Compd.*, 2008, **448**, 1.
- 30 M. Prevel, S. E. Reddy, O. Perez and W. Kobayashi, *Jpn. J. Appl. Phys.*, 2007, **46**, 6533.
- 31 F. Delorme, C. F. Martin, P. Marudhachalam, D. O. Ovono and G. Guzman, *J. Alloys Compd.*, 2011, **509**, 2311.
- 32 S. Demirel, E. Altin, E. Oz, S. Altin and A. Bayri, *J. Alloys Compd.*, 2015, **627**, 430.
- 33 Y. Wang, P. Sui, P. Ren, L. Wang, X. J. Wang, W. H. Su and H. J. Fan, *Chem. Mater.*, 2010, **22**, 1155.
- 34 B. C. Zhao, Y. P. Sun and W. H. Song, *J. Appl. Phys.*, 2006, **99**, 073906.
- 35 R. Tian, R. Donelson, C. D. Ling, E. R. Blanchard, T. Zhang, D. Chu, T. T. Tan and S. Li, *J. Phys. Chem. C*, 2013, **117**, 13382.
- 36 Y. Fu, B. Zhao, Y. Huang, J. Yang, J. Dai, M. Zhou and Y. Sun, *Solid State Commun.*, 2011, **151**, 933.
- 37 Y. Fu, B. Zhao, Y. Huang, J. Dai and Y. Sun, *Phys. B*, 2013, **414**, 16.
- 38 Y. Huang, B. Zhao, R. Ang, S. Lin, Z. H. Huang, L. Yin, S. Tan, Y. Liu, W. Song and Y. Sun, *J. Am. Ceram. Soc.*, 2013, **96**, 791.
- 39 Y. Huang, B. Zaho, R. Ang, S. Lin, W. Song and Y. Sun, *J. Alloys Compd.*, 2013, **574**, 233.
- 40 Y. Ou, J. Peng, F. Li, Z. X. Yu, F. Y. Ma, S. H. Xie, J. F. Li and J. Y. Li, *J. Alloys Compd.*, 2012, **526**, 139.
- 41 S. Butt, Y. C. Liu, J. L. Lan, K. Shehzad, B. Zhan, Y. Lin and C. W. Nan, *J. Alloys Compd.*, 2014, **588**, 277.
- 42 N. Y. Wu, N. V. Nong, N. Pryds and S. Linderoth, *J. Alloys Compd.*, 2015, **638**, 127.
- 43 M. D. Petricek and L. Palatinous, *JANA2006, The Crystallographic Computing System*, Institute of Physics, Praha, Czech Republic, 2006.
- 44 T. Wu, T. Tyson, J. M. Bai, K. Pandya, C. Jaye and D. A. Fischer, *J. Mater. Chem. C*, 2013, **1**, 4114.
- 45 R. D. Shannon, *Acta Crystallogr., Sect. A: Cryst. Phys., Diffr., Theor. Gen. Crystallogr.*, 1976, **32**, 751.
- 46 S. Li, R. Funahashi, I. Matsubara, K. Ueno, S. Sodeoka and H. Yamada, *Chem. Mater.*, 2000, **12**, 2424.
- 47 P. Limelette, J. C. Soret, H. Muguerra and D. Grebille, *Phys. Rev. B: Condens. Matter Mater. Phys.*, 2008, **77**, 245123.
- 48 Y. Wakisaka, S. Hirata, T. Mizokawa, Y. Suzuki, Y. Miyazaki and T. Kajitani, *Phys. Rev. B: Condens. Matter Mater. Phys.*, 2008, **78**, 255107.
- 49 D. Marani, R. H. Silva, A. Dankeaw, K. Norman, R. M. L. Wercheister, D. Ippolito, M. Gudik-Sørensen, K. K. Hansen and V. Esposito, *New J. Chem.*, 2017, **41**, 3466.



- 50 T. Mizokawa, L. H. Tjeng, H.-J. Lin, C. T. Chen, R. Kitawaki, I. Terasaki, S. Lambert and C. Michel, *Phys. Rev. B: Condens. Matter Mater. Phys.*, 2005, **71**, 193107.
- 51 C. S. Lim, C. K. Chua, Z. Sofer, O. Jankovský and M. Pumera, *Chem. Mater.*, 2014, **26**, 4230.
- 52 Y. Huang, B. Zhao, X. Hu, S. Lin, R. Ang, W. Song and Y. Sun, *Dalton Trans.*, 2012, **41**, 11176.
- 53 T. Wu, T. A. Tyson, H. Chen, J. Bai, H. Wang and C. Jaye, *J. Phys.: Condens. Matter*, 2012, **24**, 455602.
- 54 N. F. Mott and E. A. Davis, *Electronic Processes in Non-Crystalline Materials*, Clarendon Press, Oxford, 1971.
- 55 H. Q. Liu, X. B. Zhao, T. J. Zhu, Y. Song and F. P. Wang, *Curr. Appl. Phys.*, 2009, **9**, 409.
- 56 F. P. Zhang, X. Zhang, Q. M. Lu, J. X. Zhang, Y. Q. Liu and G. Z. Zhang, *Solid State Ionics*, 2011, **201**, 1.
- 57 G. C. McIntosh and A. B. Kaiser, *Phys. Rev. B: Condens. Matter Mater. Phys.*, 1996, **54**, 12569.
- 58 N. W. Aschcroft and N. D. Mermin, *Solid State Phys*, Philadelphia, Saunders, 1976.
- 59 Y. Wang, Y. Sui, X. Wang, W. Su and X. Liu, *J. Appl. Phys.*, 2014, **107**, 033708.
- 60 A. F. May and G. J. Synder, Introduction to Modelling Thermoelectric Transport at High Temperatures in *Thermoelectrics and its Energy Harvesting*, ed. D. M. Rowe, CRC Press, Boca Raton, 2012.
- 61 S. H. Rasekh, M. A. Torres, G. Constantinescu, M. A. Madre, J. C. Diez and A. Sotelo, *J. Mater. Sci.: Mater. Electron.*, 2013, **24**, 2309.
- 62 Y. Masuda, D. Nagahama, H. Itahara, T. Tani, W. S. Seo and K. Koumoto, *J. Mater. Chem.*, 2003, **13**, 1094.
- 63 H. Q. Liu, X. B. Zhao, T. J. Zhu, Y. Song and F. P. Wang, *Curr. Appl. Phys.*, 2009, **9**, 409.
- 64 S. Porokhin, L. Shvanskaya, V. Khovaylo and A. Vasiliev, *J. Alloys Compd.*, 2017, **695**, 2844.

